# Exercise 7.3-1

# **All Quick Questions to**

## 7. Si MEMS

#### Products and Developments

- How large is the <u>resistance of a 1 pF capacitor</u> at 10 GHZ?
- Consider that the layer of whatever it is that forms the cantilever in the picture above would be under <u>tensile stress</u> in its top part (maybe the cantilever consists of two different materials stacked on top of each other). What would happen?
- Calculate  $\Delta R/R$  for a rectangular piece of material with length *I*, width *w*, thickness *t* and specific resistivity  $\rho$  that is strained by  $\epsilon$  in *I*-direction.
- Give examples of **MEMS** products, their working principles and raneg of applications.
- Describe the working principle of a DLP beamer. Consider strengths and problems.
- Describe the working prinicple of a MEMS gyro. Provide a rough sketch of a possible implementation.
- Describe possibilites for inducing and detecting mechanical movment in a MEMS device.
- Compare a gyro or acceleration sensor operated around resonance or at lower than resoance frequencies. Give curves of amplitude and damping as a function of frequency and discuss the role of damping.
- Give some pricnciples for making actors and compare the relative merits of the approach.

### Processes and Specialities

What is "stiction" and what role does it play in MEMS technology?